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Understanding Embedded - FPGAs (Field Programmable Gate Array)

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications,

Details	
Product Status	Obsolete
Number of LABs/CLBs	1536
Number of Logic Elements/Cells	6912
Total RAM Bits	131072
Number of I/O	316
Number of Gates	411955
Voltage - Supply	1.71V ~ 1.89V
Mounting Type	Surface Mount
Operating Temperature	0°C ~ 85°C (TJ)
Package / Case	432-LBGA Exposed Pad, Metal
Supplier Device Package	432-MBGA (40x40)
Purchase URL	https://www.e-xfl.com/product-detail/xilinx/xcv300e-6bg432c

Table 1: **Virtex-E Field-Programmable Gate Array Family Members**

Device	System Gates	Logic Gates	CLB Array	Logic Cells	Differential I/O Pairs	User I/O	BlockRAM Bits	Distributed RAM Bits
XCV50E	71,693	20,736	16 x 24	1,728	83	176	65,536	24,576
XCV100E	128,236	32,400	20 x 30	2,700	83	196	81,920	38,400
XCV200E	306,393	63,504	28 x 42	5,292	119	284	114,688	75,264
XCV300E	411,955	82,944	32 x 48	6,912	137	316	131,072	98,304
XCV400E	569,952	129,600	40 x 60	10,800	183	404	163,840	153,600
XCV600E	985,882	186,624	48 x 72	15,552	247	512	294,912	221,184
XCV1000E	1,569,178	331,776	64 x 96	27,648	281	660	393,216	393,216
XCV1600E	2,188,742	419,904	72 x 108	34,992	344	724	589,824	497,664
XCV2000E	2,541,952	518,400	80 x 120	43,200	344	804	655,360	614,400
XCV2600E	3,263,755	685,584	92 x 138	57,132	344	804	753,664	812,544
XCV3200E	4,074,387	876,096	104 x 156	73,008	344	804	851,968	1,038,336

Virtex-E Compared to Virtex Devices

The Virtex-E family offers up to 43,200 logic cells in devices up to 30% faster than the Virtex family.

I/O performance is increased to 622 Mb/s using Source Synchronous data transmission architectures and synchronous system performance up to 240 MHz using singled-ended SelectI/O technology. Additional I/O standards are supported, notably LVPECL, LVDS, and BLVDS, which use two pins per signal. Almost all signal pins can be used for these new standards.

Virtex-E devices have up to 640 Kb of faster (250 MHz) block SelectRAM, but the individual RAMs are the same size and structure as in the Virtex family. They also have eight DLLs instead of the four in Virtex devices. Each individual DLL is slightly improved with easier clock mirroring and 4x frequency multiplication.

V_{CCINT}, the supply voltage for the internal logic and memory, is 1.8 V, instead of 2.5 V for Virtex devices. Advanced processing and 0.18 μm design rules have resulted in smaller dice, faster speed, and lower power consumption.

I/O pins are 3 V tolerant, and can be 5 V tolerant with an external 100 Ω resistor. PCI 5 V is not supported. With the addition of appropriate external resistors, any pin can tolerate any voltage desired.

Banking rules are different. With Virtex devices, all input buffers are powered by V_{CCINT}. With Virtex-E devices, the LVTTL, LVCMOS2, and PCI input buffers are powered by the I/O supply voltage V_{CCO}.

The Virtex-E family is not bitstream-compatible with the Virtex family, but Virtex designs can be compiled into equivalent Virtex-E devices.

The same device in the same package for the Virtex-E and Virtex families are pin-compatible with some minor exceptions. See the data sheet pinout section for details.

General Description

The Virtex-E FPGA family delivers high-performance, high-capacity programmable logic solutions. Dramatic increases in silicon efficiency result from optimizing the new architecture for place-and-route efficiency and exploiting an aggressive 6-layer metal 0.18 μm CMOS process. These advances make Virtex-E FPGAs powerful and flexible alternatives to mask-programmed gate arrays. The Virtex-E family includes the nine members in Table 1.

Building on experience gained from Virtex FPGAs, the Virtex-E family is an evolutionary step forward in programmable logic design. Combining a wide variety of programmable system features, a rich hierarchy of fast, flexible interconnect resources, and advanced process technology, the Virtex-E family delivers a high-speed and high-capacity programmable logic solution that enhances design flexibility while reducing time-to-market.

Virtex-E Architecture

Virtex-E devices feature a flexible, regular architecture that comprises an array of configurable logic blocks (CLBs) surrounded by programmable input/output blocks (IOBs), all interconnected by a rich hierarchy of fast, versatile routing

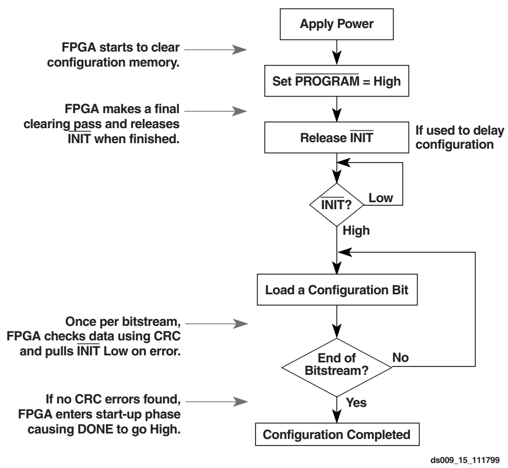

Figure 15: **Serial Configuration Flowchart**

Figure 16 shows the timing of master-serial configuration. Master-serial mode is selected by a <000> or <100> on the mode pins (M2, M1, M0). Table 10 shows the timing information for Figure 16.

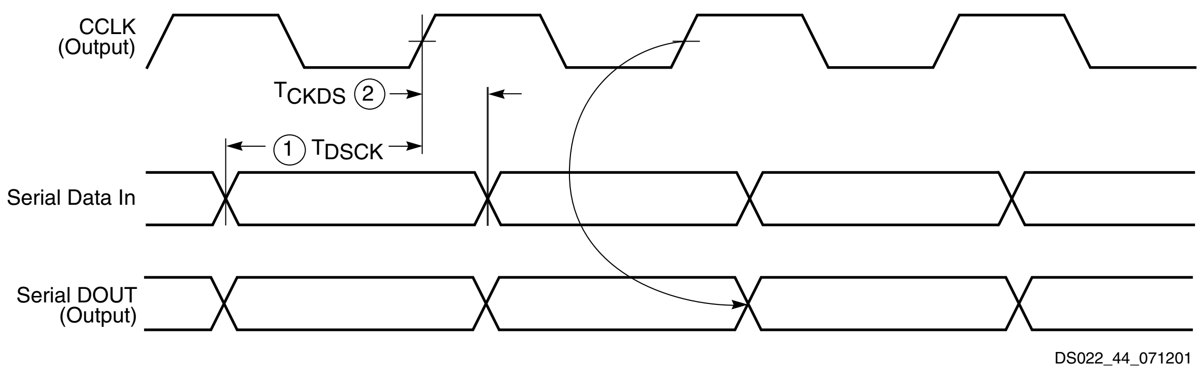

Figure 16: **Master-Serial Mode Programming Switching Characteristics**

At power-up, V_{CC} must rise from 1.0 V to V_{CC} Min in less than 50 ms, otherwise delay configuration by pulling PROGRAM Low until V_{CC} is valid.

SelectMAP Mode

The SelectMAP mode is the fastest configuration option. Byte-wide data is written into the FPGA with a BUSY flag controlling the flow of data.

An external data source provides a byte stream, CCLK, a Chip Select (CS) signal and a Write signal (WRITE). If BUSY is asserted (High) by the FPGA, the data must be held until BUSY goes Low.

Data can also be read using the SelectMAP mode. If WRITE is not asserted, configuration data is read out of the FPGA as part of a readback operation.

After configuration, the pins of the SelectMAP port can be used as additional user I/O. Alternatively, the port can be retained to permit high-speed 8-bit readback.

Retention of the SelectMAP port is selectable on a design-by-design basis when the bitstream is generated. If retention is selected, PROHIBIT constraints are required to prevent the SelectMAP-port pins from being used as user I/O.

Multiple Virtex-E FPGAs can be configured using the SelectMAP mode, and be made to start-up simultaneously. To configure multiple devices in this way, wire the individual CCLK, Data, WRITE, and BUSY pins of all the devices in parallel. The individual devices are loaded separately by asserting the CS pin of each device in turn and writing the appropriate data. See Table 11 for SelectMAP Write Timing Characteristics.

Write

Write operations send packets of configuration data into the FPGA. The sequence of operations for a multi-cycle write operation is shown below. Note that a configuration packet can be split into many such sequences. The packet does not have to complete within one assertion of CS, illustrated in Figure 17.

1. Assert WRITE and CS Low. Note that when CS is asserted on successive CCLKs, WRITE must remain either asserted or de-asserted. Otherwise, an abort is initiated, as described below.
2. Drive data onto D[7:0]. Note that to avoid contention, the data source should not be enabled while CS is Low and WRITE is High. Similarly, while WRITE is High, no more that one CS should be asserted.

ground. As the DLL delay taps reset to zero, glitches can occur on the DLL clock output pins. Activation of the RST pin can also severely affect the duty cycle of the clock output pins. Furthermore, the DLL output clocks no longer deskew with respect to one another. For these reasons, rarely use the reset pin unless re-configuring the device or changing the input frequency.

2x Clock Output — CLK2X

The output pin CLK2X provides a frequency-doubled clock with an automatic 50/50 duty-cycle correction. Until the CLKDLL has achieved lock, the CLK2X output appears as a 1x version of the input clock with a 25/75 duty cycle. This behavior allows the DLL to lock on the correct edge with respect to source clock. This pin is not available on the CLKDLLHF primitive.

Clock Divide Output — CLKDV

The clock divide output pin CLKDV provides a lower frequency version of the source clock. The CLKDV_DIVIDE property controls CLKDV such that the source clock is divided by N where N is either 1.5, 2, 2.5, 3, 4, 5, 8, or 16.

This feature provides automatic duty cycle correction such that the CLKDV output pin always has a 50/50 duty cycle, with the exception of noninteger divides in HF mode, where the duty cycle is 1/3 for N=1.5 and 2/5 for N=2.5.

1x Clock Outputs — CLK[0|90|180|270]

The 1x clock output pin CLK0 represents a delay-compensated version of the source clock (CLKIN) signal. The CLKDLL primitive provides three phase-shifted versions of the CLK0 signal while CLKDLLHF provides only the 180 phase-shifted version. The relationship between phase shift and the corresponding period shift appears in Table 13.

Table 13: **Relationship of Phase-Shifted Output Clock to Period Shift**

Phase (degrees)	Period Shift (percent)
0	0%
90	25%
180	50%
270	75%

The timing diagrams in Figure 25 illustrate the DLL clock output characteristics.

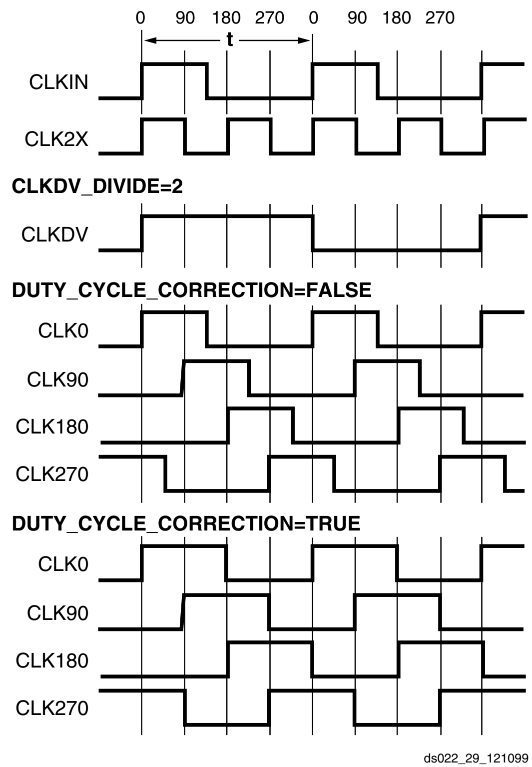

Figure 25: **DLL Output Characteristics**

The DLL provides duty cycle correction on all 1x clock outputs such that all 1x clock outputs by default have a 50/50 duty cycle. The DUTY_CYCLE_CORRECTION property (TRUE by default), controls this feature. In order to deactivate the DLL duty cycle correction, attach the DUTY_CYCLE_CORRECTION=FALSE property to the DLL symbol. When duty cycle correction deactivates, the output clock has the same duty cycle as the source clock.

The DLL clock outputs can drive an OBUF, a BUFG, or they can route directly to destination clock pins. The DLL clock outputs can only drive the BUFGs that reside on the same edge (top or bottom).

Locked Output — LOCKED

To achieve lock, the DLL might need to sample several thousand clock cycles. After the DLL achieves lock, the LOCKED signal activates. The DLL timing parameter section of the data sheet provides estimates for locking times.

To guarantee that the system clock is established prior to the device "waking up," the DLL can delay the completion of the device configuration process until after the DLL locks. The STARTUP_WAIT property activates this feature.

Until the LOCKED signal activates, the DLL output clocks are not valid and can exhibit glitches, spikes, or other spurious movement. In particular the CLK2X output appears as a 1x clock with a 25/75 duty cycle.

Data Output Bus—DO[A|B]<#:0>

The data out bus reflects the contents of the memory cells referenced by the address bus at the last active clock edge. During a write operation, the data out bus reflects the data in bus. The width of this bus equals the width of the port. The allowed widths appear in Table 15.

Inverting Control Pins

The four control pins (CLK, EN, WE and RST) for each port have independent inversion control as a configuration option.

Address Mapping

Each port accesses the same set of 4096 memory cells using an addressing scheme dependent on the width of the port.

The physical RAM location addressed for a particular width are described in the following formula (of interest only when the two ports use different aspect ratios).

$$Start = ((ADDR_{port} +1) * Width_{port}) -1$$

$$End = ADDR_{port} * Width_{port}$$

Table 16 shows low order address mapping for each port width.

Table 16: **Port Address Mapping**

Port Width	Port Addresses																
1	4095...	15	14	13	12	11	10	09	08	07	06	05	04	03	02	01	00
2	2047...	07		06		05		04		03		02		01		00	
4	1023...	03				02				01				00			
8	511...	01								00							
16	255...	00															

Creating Larger RAM Structures

The block SelectRAM+ columns have specialized routing to allow cascading blocks together with minimal routing delays. This achieves wider or deeper RAM structures with a smaller timing penalty than when using normal routing channels.

Location Constraints

Block SelectRAM+ instances can have LOC properties attached to them to constrain the placement. The block SelectRAM+ placement locations are separate from the CLB location naming convention, allowing the LOC properties to transfer easily from array to array.

The LOC properties use the following form.

LOC = RAMB4_R#C#

RAMB4_R0C0 is the upper left RAMB4 location on the device.

Conflict Resolution

The block SelectRAM+ memory is a true dual-read/write port RAM that allows simultaneous access of the same memory cell from both ports. When one port writes to a given memory cell, the other port must not address that memory cell (for a write or a read) within the clock-to-clock setup window. The following lists specifics of port and memory cell write conflict resolution.

- If both ports write to the same memory cell simultaneously, violating the clock-to-clock setup requirement, consider the data stored as invalid.
- If one port attempts a read of the same memory cell the other simultaneously writes, violating the clock-to-clock setup requirement, the following occurs.
  - The write succeeds
  - The data out on the writing port accurately reflects the data written.
  - The data out on the reading port is invalid.

Conflicts do not cause any physical damage.

Single Port Timing

Figure 33 shows a timing diagram for a single port of a block SelectRAM+ memory. The block SelectRAM+ AC switching characteristics are specified in the data sheet. The block SelectRAM+ memory is initially disabled.

At the first rising edge of the CLK pin, the ADDR, DI, EN, WE, and RST pins are sampled. The EN pin is High and the WE pin is Low indicating a read operation. The DO bus contains the contents of the memory location, 0x00, as indicated by the ADDR bus.

At the second rising edge of the CLK pin, the ADDR, DI, EN, WR, and RST pins are sampled again. The EN and WE pins are High indicating a write operation. The DO bus mirrors the DI bus. The DI bus is written to the memory location 0x0F.

At the third rising edge of the CLK pin, the ADDR, DI, EN, WR, and RST pins are sampled again. The EN pin is High and the WE pin is Low indicating a read operation. The DO bus contains the contents of the memory location 0x7E as indicated by the ADDR bus.

At the fourth rising edge of the CLK pin, the ADDR, DI, EN, WR, and RST pins are sampled again. The EN pin is Low

SSTL3_I

A sample circuit illustrating a valid termination technique for SSTL3_I appears in Figure 49. DC voltage specifications appear in Table 28.

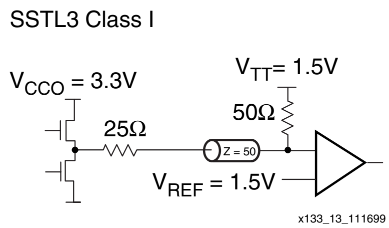

Figure 49: **Terminated SSTL3 Class I**

Table 28: **SSTL3_I Voltage Specifications**

Parameter	Min	Typ	Max
V_{CCO}	**3.0**	**3.3**	**3.6**
$V_{REF} = 0.45 \times V_{CCO}$	1.3	1.5	1.7
$V_{TT} = V_{REF}$	1.3	1.5	1.7
$V_{IH} = V_{REF} + 0.2$	1.5	1.7	3.9(1)
$V_{IL} = V_{REF} – 0.2$	–0.3(2)	1.3	1.5
$V_{OH} = V_{REF} + 0.6$	1.9	-	-
$V_{OL} = V_{REF} – 0.6$	-	-	1.1
I_{OH} at V_{OH} (mA)	–8	-	-
I_{OL}at V_{OL} (mA)	8	-	-

Notes:
1. V_{IH} maximum is V_{CCO} + 0.3
2. V_{IL} minimum does not conform to the formula

SSTL3_II

A sample circuit illustrating a valid termination technique for SSTL3_II appears in Figure 50. DC voltage specifications appear in Table 29.

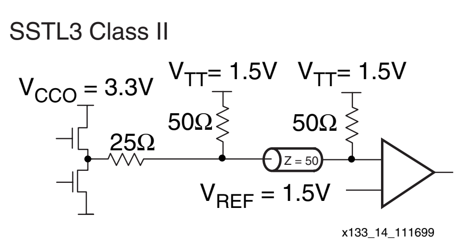

Figure 50: **Terminated SSTL3 Class II**

Table 29: **SSTL3_II Voltage Specifications**

Parameter	Min	Typ	Max
V_{CCO}	3.0	3.3	3.6
$V_{REF} = 0.45 \times V_{CCO}$	1.3	1.5	1.7
$V_{TT} = V_{REF}$	1.3	1.5	1.7
$V_{IH} = V_{REF} + 0.2$	1.5	1.7	3.9(1)
$V_{IL}= V_{REF} – 0.2$	–0.3(2)	1.3	1.5
$V_{OH} = V_{REF} + 0.8$	2.1	-	-
$V_{OL}= V_{REF} – 0.8$	-	-	0.9
I_{OH} at V_{OH} (mA)	–16	-	-
I_{OL}at V_{OL} (mA)	16	-	-

Notes:
1. V_{IH} maximum is V_{CCO} + 0.3
2. V_{IL} minimum does not conform to the formula

SSTL2_I

A sample circuit illustrating a valid termination technique for SSTL2_I appears in Figure 51. DC voltage specifications appear in Table 30.

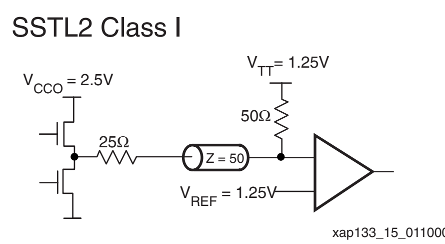

Figure 51: **Terminated SSTL2 Class I**

Table 30: **SSTL2_I Voltage Specifications**

Parameter	Min	Typ	Max
V_{CCO}	2.3	2.5	2.7
$V_{REF} = 0.5 \times V_{CCO}$	1.15	1.25	1.35
$V_{TT} = V_{REF} + N^{(1)}$	1.11	1.25	1.39
$V_{IH} = V_{REF} + 0.18$	1.33	1.43	3.0(2)
$V_{IL} = V_{REF} – 0.18$	–0.3(3)	1.07	1.17
$V_{OH} = V_{REF} + 0.61$	1.76	-	-
$V_{OL}= V_{REF} – 0.61$	-	-	0.74
I_{OH} at V_{OH} (mA)	–7.6	-	-
I_{OL}at V_{OL} (mA)	7.6	-	-

Notes:
1. N must be greater than or equal to -0.04 and less than or equal to 0.04.
2. V_{IH} maximum is V_{CCO} + 0.3.
3. V_{IL} minimum does not conform to the formula.

LVTTL

LVTTL requires no termination. DC voltage specifications appears in Table 34.

Table 34: **LVTTL Voltage Specifications**

Parameter	Min	Typ	Max
V_{CCO}	3.0	3.3	3.6
V_{REF}	-	-	-
V_{TT}	-	-	-
V_{IH}	2.0	-	3.6
V_{IL}	–0.5	-	0.8
V_{OH}	2.4	-	-
V_{OL}	-	-	0.4
I_{OH} at V_{OH} (mA)	–24	-	-
I_{OL}at V_{OL} (mA)	24	-	-

Notes:
1. Note: $V_{OL}$and V_{OH} for lower drive currents sample tested.

LVCMOS2

LVCMOS2 requires no termination. DC voltage specifications appear in Table 35.

Table 35: **LVCMOS2 Voltage Specifications**

Parameter	Min	Typ	Max
V_{CCO}	2.3	2.5	2.7
V_{REF}	-	-	-
V_{TT}	-	-	-
V_{IH}	1.7	-	3.6
V_{IL}	–0.5	-	0.7
V_{OH}	1.9	-	-
V_{OL}	-	-	0.4
I_{OH} at V_{OH} (mA)	–12	-	-
I_{OL}at V_{OL} (mA)	12	-	-

LVCMOS18

LVCMOS18 does not require termination. Table 36 lists DC voltage specifications.

Table 36: **LVCMOS18 Voltage Specifications**

Parameter	Min	Typ	Max
V_{CCO}	1.70	1.80	1.90
V_{REF}	-	-	-
V_{TT}	-	-	-
V_{IH}	0.65 x V_{CCO}	-	1.95
V_{IL}	– 0.5	-	0.2 x V_{CCO}
V_{OH}	V_{CCO} – 0.4	-	-
V_{OL}	-	-	0.4
I_{OH} at V_{OH} (mA)	–8	-	-
I_{OL}at V_{OL} (mA)	8	-	-

AGP-2X

The specification for the AGP-2X standard does not document a recommended termination technique. DC voltage specifications appear in Table 37.

Table 37: **AGP-2X Voltage Specifications**

Parameter	Min	Typ	Max
V_{CCO}	3.0	3.3	3.6
$V_{REF} = N \times V_{CCO}$[1]	1.17	1.32	1.48
V_{TT}	-	-	-
$V_{IH} = V_{REF} + 0.2$	1.37	1.52	-
$V_{IL} = V_{REF} - 0.2$	-	1.12	1.28
$V_{OH} = 0.9 \times V_{CCO}$	2.7	3.0	-
$V_{OL} = 0.1 \times V_{CCO}$	-	0.33	0.36
I_{OH} at V_{OH} (mA)	Note 2	-	-
I_{OL}at V_{OL} (mA)	Note 2	-	-

Notes:
1. N must be greater than or equal to 0.39 and less than or equal to 0.41.
2. Tested according to the relevant specification.

Global Clock Input to Output Delay for LVTTL, 12 mA, Fast Slew Rate, *without* DLL

Description[(1)]	Symbol	Device	Speed Grade[(2)]				Units
			Min	-8	-7	-6	
LVTTL Global Clock Input to Output Delay using Output Flip-flop, 12 mA, Fast Slew Rate, *without* DLL. For data *output* with different standards, adjust the delays with the values shown in **IOB Output Switching Characteristics Standard Adjustments**, page 10.	T_{ICKOF}	XCV50E	1.5	4.2	4.4	4.6	ns
		XCV100E	1.5	4.2	4.4	4.6	ns
		XCV200E	1.5	4.3	4.5	4.7	ns
		XCV300E	1.5	4.3	4.5	4.7	ns
		XCV400E	1.5	4.4	4.6	4.8	ns
		XCV600E	1.6	4.5	4.7	4.9	ns
		XCV1000E	1.7	4.6	4.8	5.0	ns
		XCV1600E	1.8	4.7	4.9	5.1	ns
		XCV2000E	1.8	4.8	5.0	5.2	ns
		XCV2600E	2.0	5.0	5.2	5.4	ns
		XCV3200E	2.2	5.2	5.4	5.6	ns

Notes:

1. Listed above are representative values where one global clock input drives one vertical clock line in each accessible column, and where all accessible IOB and CLB flip-flops are clocked by the global clock net.
2. Output timing is measured at 50% V_{CC} threshold with 35 pF external capacitive load. For other I/O standards and different loads, see Table 3 and Table 4.

PQ240 Differential Pin Pairs

Virtex-E devices have differential pin pairs that can also provide other functions when not used as a differential pair. A √ in the AO column indicates that the pin pair can be used as an asynchronous output for all devices provided in this package. Pairs with a note number in the AO column are device dependent. They can have asynchronous outputs if the pin pair are in the same CLB row and column in the device. Numbers in this column refer to footnotes that indicate which devices have pin pairs than can be asynchronous outputs. The Other Functions column indicates alternative function(s) not available when the pair is used as a differential pair or differential clock.

Table 7: **PQ240 Differential Pin Pair Summary XCV50E, XCV100E, XCV200E, XCV300E, XCV400E**

Pair	Bank	P Pin	N Pin	AO	Other Functions
Global Differential Clock					
0	4	P92	P93	NA	IO_DLL_L40P
1	5	P89	P87	NA	IO_DLL_L40N
2	1	P210	P209	NA	IO_DLL_L6P
3	0	P213	P215	NA	IO_DLL_L6N
IO LVDS Total Pairs: 64, Asynchronous Outputs Pairs: 27					
0	0	P236	P237	1	VREF
1	0	P234	P235	√	-
2	0	P228	P229	√	VREF
3	0	P223	P224	√	-
4	0	P220	P221	3	-
5	0	P217	P218	3	VREF
6	1	P209	P215	NA	IO_LVDS_DLL
7	1	P205	P206	3	VREF
8	1	P202	P203	3	-
9	1	P199	P200	√	-
10	1	P194	P195	√	VREF
11	1	P191	P192	√	VREF
12	1	P188	P189	√	-
13	1	P186	P187	1	VREF
14	1	P184	P185	√	CS
15	2	P178	P177	√	DIN, D0

Table 7: **PQ240 Differential Pin Pair Summary XCV50E, XCV100E, XCV200E, XCV300E, XCV400E**

Pair	Bank	P Pin	N Pin	AO	Other Functions
16	2	P174	P173	2	-
17	2	P171	P170	3	VREF
18	2	P168	P167	4	D1, VREF
19	2	P163	P162	√	D2
20	2	P160	P159	2	-
21	2	P157	P156	4	D3, VREF
22	2	P155	P154	5	VREF
23	2	P153	P152	√	-
24	3	P145	P144	4	D4, VREF
25	3	P142	P141	2	-
26	3	P139	P138	√	D5
27	3	P134	P133	4	VREF
28	3	P131	P130	3	VREF
29	3	P128	P127	2	-
30	3	P126	P125	6	VREF
31	3	P124	P123	√	INIT
32	4	P118	P117	√	-
33	4	P114	P113	√	-
34	4	P111	P110	√	VREF
35	4	P108	P107	√	VREF
36	4	P103	P102	√	-
37	4	P100	P99	3	-
38	4	P97	P96	3	VREF
39	4	P95	P94	7	VREF
40	5	P93	P87	NA	IO_LVDS_DLL
41	5	P84	P82	8	VREF
42	5	P79	P78	√	-
43	5	P74	P73	√	VREF
44	5	P71	P70	√	VREF
45	5	P68	P67	√	-
46	5	P66	P65	1	VREF
47	5	P64	P63	√	-

Table 9: **HQ240 Differential Pin Pair Summary XCV600E, XCV1000E**

Pair	Bank	P Pin	N Pin	AO	Other Functions
48	6	P56	P57	√	-
49	6	P52	P53	√	-
50	6	P49	P50	√	VREF
51	6	P46	P47	√	VREF
52	6	P41	P42	√	-
53	6	P38	P39	√	-
54	6	P35	P36	√	VREF
55	6	P33	P34	1	VREF
56	7	P27	P28	√	-
57	7	P23	P24	√	VREF
58	7	P20	P21	√	-
59	7	P17	P18	√	-
60	7	P12	P13	√	VREF
61	7	P9	P10	√	VREF
62	7	P6	P7	√	-
63	7	P4	P5	1	VREF

Note 1: AO in the XCV600E.

BG352 Ball Grid Array Packages

XCV100E, XCV200E, and XCV300E devices in BG352 Ball Grid Array packages have footprint compatibility. Pins labeled I0_VREF can be used as either in all parts unless device-dependent as indicated in the footnotes. If the pin is not used as V_{REF}, it can be used as general I/O. Immediately following Table 10, see Table 11 for Differential Pair information.

Table 10: **BG352 — XCV100E, XCV200E, XCV300E**

Bank	Pin Description	Pin #
0	IO	D22
0	IO	C23[1]
0	IO	B24[1]
0	IO	C22
0	IO_VREF_0_L0N_YY	D21[2]
0	IO_L0P_YY	B23
0	IO	A24[1]
0	IO_L1N_YY	A23
0	IO_L1P_YY	D20
0	IO_VREF_0_L2N_YY	C21
0	IO_L2P_YY	B22
0	IO	B21[1]
0	IO	C20[1]
0	IO_L3N	B20
0	IO_L3P	A21
0	IO	D18
0	IO_VREF_0_L4N_YY	C19
0	IO_L4P_YY	B19
0	IO_L5N_YY	D17
0	IO_L5P_YY	C18
0	IO	B18[1]
0	IO_L6N	C17
0	IO_L6P	A18
0	IO	D16[1]
0	IO_L7N_Y	B17
0	IO_L7P_Y	C16
0	IO_VREF_0_L8N_Y	A16
0	IO_L8P_Y	D15

Table 10: **BG352 — XCV100E, XCV200E, XCV300E**

Bank	Pin Description	Pin #
NA	VCCINT	V24
NA	VCCINT	R23
NA	VCCINT	P25
NA	VCCINT	L25
NA	VCCINT	J24
0	VCCO	D19
0	VCCO	B25
0	VCCO	A17
1	VCCO	D13
1	VCCO	D7
1	VCCO	A10
2	VCCO	K1
2	VCCO	H4
2	VCCO	B2
3	VCCO	Y4
3	VCCO	U1
3	VCCO	P4
4	VCCO	AF10
4	VCCO	AE2
4	VCCO	AC8
5	VCCO	AF17
5	VCCO	AC20
5	VCCO	AC14
6	VCCO	AE25
6	VCCO	W23
6	VCCO	U26
7	VCCO	N23
7	VCCO	K26
7	VCCO	G23
NA	GND	A26
NA	GND	A25
NA	GND	A22

Table 10: **BG352 — XCV100E, XCV200E, XCV300E**

Bank	Pin Description	Pin #
NA	GND	A19
NA	GND	A14
NA	GND	A8
NA	GND	A5
NA	GND	A2
NA	GND	A1
NA	GND	B26
NA	GND	B1
NA	GND	E26
NA	GND	E1
NA	GND	H26
NA	GND	H1
NA	GND	N1
NA	GND	P26
NA	GND	W26
NA	GND	W1
NA	GND	AB26
NA	GND	AB1
NA	GND	AE26
NA	GND	AE1
NA	GND	AF26
NA	GND	AF25
NA	GND	AF22
NA	GND	AF19
NA	GND	AF13
NA	GND	AF8
NA	GND	AF5
NA	GND	AF2
NA	GND	AF1

Notes:
1. No Connect in the XCV100E.
2. V_{REF} or I/O option only in the XCV200E and XCV300E; otherwise, I/O option only.

Table 12: **BG432 — XCV300E, XCV400E, XCV600E**

Bank	Pin Description	Pin #
6	VCCO	AL31
7	VCCO	A31
7	VCCO	L28
7	VCCO	L31
NA	GND	A2
NA	GND	A3
NA	GND	A7
NA	GND	A9
NA	GND	A14
NA	GND	A18
NA	GND	A23
NA	GND	A25
NA	GND	A29
NA	GND	A30
NA	GND	B1
NA	GND	B2
NA	GND	B30
NA	GND	B31
NA	GND	C1
NA	GND	C31
NA	GND	D16
NA	GND	G1
NA	GND	G31
NA	GND	J1
NA	GND	J31
NA	GND	P1
NA	GND	P31
NA	GND	T4
NA	GND	T28
NA	GND	V1
NA	GND	V31
NA	GND	AC1
NA	GND	AC31
NA	GND	AE1
NA	GND	AE31
NA	GND	AH16
NA	GND	AJ1
NA	GND	AJ31
NA	GND	AK1
NA	GND	AK2
NA	GND	AK30
NA	GND	AK31
NA	GND	AL2
NA	GND	AL3
NA	GND	AL7
NA	GND	AL9
NA	GND	AL14
NA	GND	AL18
NA	GND	AL23
NA	GND	AL25
NA	GND	AL29
NA	GND	AL30

Notes:

1. V_{REF} or I/O option only in the XCV600E; otherwise, I/O option only.
2. V_{REF} or I/O option only in the XCV400E, XCV600E; otherwise, I/O option only.

Table 14: **BG560 — XCV400E, XCV600E, XCV1000E, XCV1600E, XCV2000E**

Bank	Pin Description	Pin#	See Note
3	IO_D4_L73P_YY	W4	
3	IO_VREF_L73N_YY	W5	
3	IO_L74P_Y	Y3	
3	IO_L74N_Y	Y4	
3	IO_L75P_Y	AA1	
3	IO_L75N_Y	Y5	
3	IO_L76P_Y	AA3	
3	IO_VREF_L76N_Y	AA4	3
3	IO_L77P_Y	AB3	
3	IO_L77N_Y	AA5	
3	IO_L78P_Y	AC1	
3	IO_L78N_Y	AB4	
3	IO_L79P_YY	AC3	
3	IO_D5_L79N_YY	AB5	
3	IO_D6_L80P_YY	AC4	
3	IO_VREF_L80N_YY	AD3	
3	IO_L81P_Y	AE1	
3	IO_L81N_Y	AC5	
3	IO_L82P_Y	AD4	
3	IO_VREF_L82N_Y	AF1	4
3	IO_L83P_Y	AF2	
3	IO_L83N_Y	AD5	
3	IO_L84P_Y	AG2	
3	IO_VREF_L84N_Y	AE4	1
3	IO_L85P_YY	AH1	
3	IO_VREF_L85N_YY	AE5	
3	IO_L86P_Y	AF4	
3	IO_L86N_Y	AJ1	
3	IO_L87P_Y	AJ2	
3	IO_L87N_Y	AF5	
3	IO_L88P_Y	AG4	
3	IO_VREF_L88N_Y	AK2	
3	IO_L89P_Y	AJ3	
3	IO_L89N_Y	AG5	
3	IO_L90P_Y	AL1	
3	IO_VREF_L90N_Y	AH4	3
3	IO_D7_L91P_YY	AJ4	
3	IO_INIT_L91N_YY	AH5	
3	IO	U4	
4	GCK0	AL17	
4	IO	AJ8	
4	IO	AJ11	
4	IO	AK6	
4	IO	AK9	
4	IO_L92P_YY	AL4	
4	IO_L92N_YY	AJ6	
4	IO_L93P_Y	AK5	
4	IO_VREF_L93N_Y	AN3	3
4	IO_L94P_YY	AL5	
4	IO_L94N_YY	AJ7	
4	IO_VREF_L95P_YY	AM4	
4	IO_L95N_YY	AM5	
4	IO_L96P_Y	AK7	
4	IO_L96N_Y	AL6	
4	IO_L97P_YY	AM6	
4	IO_L97N_YY	AN6	
4	IO_VREF_L98P_YY	AL7	
4	IO_L98N_YY	AJ9	
4	IO_L99P_Y	AN7	
4	IO_VREF_L99N_Y	AL8	1
4	IO_L100P_Y	AM8	
4	IO_L100N_Y	AJ10	
4	IO_VREF_L101P_Y	AL9	4
4	IO_L101N_Y	AM9	
4	IO_L102P_Y	AK10	
4	IO_L102N_Y	AN9	
4	IO_VREF_L103P_YY	AL10	
4	IO_L103N_YY	AM10	
4	IO_L104P_YY	AL11	

Table 14: **BG560 — XCV400E, XCV600E, XCV1000E, XCV1600E, XCV2000E**

Bank	Pin Description	Pin#	See Note
7	IO_L165N_YY	P32	
7	IO_VREF_L165P_YY	P31	
7	IO_L166N_Y	P30	
7	IO_L166P_Y	P29	
7	IO_L167N_Y	M32	
7	IO_L167P_Y	N31	
7	IO_L168N_Y	N30	
7	IO_VREF_L168P_Y	L33	3
7	IO_L169N_Y	M31	
7	IO_L169P_Y	L32	
7	IO_L170N_Y	M30	
7	IO_L170P_Y	L31	
7	IO_L171N_YY	M29	
7	IO_L171P_YY	J33	
7	IO_L172N_YY	L30	
7	IO_VREF_L172P_YY	K31	
7	IO_L173N_Y	L29	
7	IO_L173P_Y	H33	
7	IO_L174N_Y	J31	
7	IO_VREF_L174P_Y	H32	4
7	IO_L175N_Y	K29	
7	IO_L175P_Y	H31	
7	IO_L176N_Y	J30	
7	IO_VREF_L176P_Y	G32	1
7	IO_L177N_YY	J29	
7	IO_VREF_L177P_YY	G31	
7	IO_L178N_Y	E33	
7	IO_L178P_Y	E32	
7	IO_L179N_Y	H29	
7	IO_L179P_Y	F31	
7	IO_L180N_Y	D32	
7	IO_VREF_L180P_Y	E31	
7	IO_L181N_Y	G29	
7	IO_L181P_Y	C33	
7	IO_L182N_Y	F30	

Table 14: **BG560 — XCV400E, XCV600E, XCV1000E, XCV1600E, XCV2000E**

Bank	Pin Description	Pin#	See Note
7	IO_VREF_L182P_Y	D31	3
2	CCLK	C4	
3	DONE	AJ5	
NA	DXN	AK29	
NA	DXP	AJ28	
NA	M0	AJ29	
NA	M1	AK30	
NA	M2	AN32	
NA	PROGRAM	AM1	
NA	TCK	E29	
NA	TDI	D5	
2	TDO	E6	
NA	TMS	B33	
NA	NC	C31	
NA	NC	AC2	
NA	NC	AK4	
NA	NC	AL3	
NA	VCCINT	A21	
NA	VCCINT	B12	
NA	VCCINT	B14	
NA	VCCINT	B18	
NA	VCCINT	B28	
NA	VCCINT	C22	
NA	VCCINT	C24	
NA	VCCINT	E9	
NA	VCCINT	E12	
NA	VCCINT	F2	
NA	VCCINT	H30	
NA	VCCINT	J1	
NA	VCCINT	K32	
NA	VCCINT	M3	
NA	VCCINT	N1	

FG680 Fine-Pitch Ball Grid Array Package

XCV600E, XCV1000E, XCV1600E, and XCV2000E devices in the FG680 fine-pitch Ball Grid Array package have footprint compatibility. Pins labeled I0_VREF can be used as either in all parts unless device-dependent as indicated in the footnotes. If the pin is not used as V_{REF}, it can be used as general I/O. Immediately following Table 22, see Table 23 for Differential Pair information.

Table 22: **FG680 - XCV600E, XCV1000E, XCV1600E, XCV2000E**

Bank	Pin Description	Pin #
0	GCK3	A20
0	IO	D35
0	IO	B36
0	IO_L0N_Y	C35
0	IO_L0P_Y	A36
0	IO_VREF_L1N_Y	D34[1]
0	IO_L1P_Y	B35
0	IO_L2N_YY	C34
0	IO_L2P_YY	A35
0	IO_VREF_L3N_YY	D33
0	IO_L3P_YY	B34
0	IO_L4N	C33
0	IO_L4P	A34
0	IO_L5N_Y	D32
0	IO_L5P_Y	B33
0	IO_L6N_YY	C32
0	IO_L6P_YY	D31
0	IO_VREF_L7N_YY	A33
0	IO_L7P_YY	C31
0	IO_L8N_Y	B32
0	IO_L8P_Y	B31
0	IO_VREF_L9N_Y	A32[3]
0	IO_L9P_Y	D30
0	IO_L10N_YY	A31
0	IO_L10P_YY	C30
0	IO_VREF_L11N_YY	B30
0	IO_L11P_YY	D29
0	IO_L12N_Y	A30
0	IO_L12P_Y	C29
0	IO_L13N_Y	A29
0	IO_L13P_Y	B29
0	IO_VREF_L14N_YY	B28
0	IO_L14P_YY	A28
0	IO_L15N_YY	C28
0	IO_L15P_YY	B27
0	IO_L16N_Y	D27
0	IO_L16P_Y	A27
0	IO_L17N_Y	C27
0	IO_L17P_Y	B26
0	IO_L18N_YY	D26
0	IO_L18P_YY	C26
0	IO_VREF_L19N_YY	A26[1]
0	IO_L19P_YY	D25
0	IO_L20N_Y	B25
0	IO_L20P_Y	C25
0	IO_L21N_Y	A25
0	IO_L21P_Y	D24
0	IO_L22N_YY	A24
0	IO_L22P_YY	B23
0	IO_VREF_L23N_YY	C24
0	IO_L23P_YY	A23
0	IO_L24N_Y	B24
0	IO_L24P_Y	B22
0	IO_L25N_Y	E23
0	IO_L25P_Y	A22
0	IO_L26N_YY	D23
0	IO_L26P_YY	B21
0	IO_VREF_L27N_YY	C23
0	IO_L27P_YY	A21
0	IO_L28N_Y	E22
0	IO_L28P_Y	B20
0	IO_LVDS_DLL_L29N	C22
0	IO_VREF	D22[2]
1	GCK2	D21

Table 22: **FG680 - XCV600E, XCV1000E, XCV1600E, XCV2000E**

Table 22: **FG680 - XCV600E, XCV1000E, XCV1600E, XCV2000E**

Bank	Pin Description	Pin #
1	IO	C5
1	IO_LVDS_DLL_L29P	A19
1	IO_L30N_Y	C21
1	IO_VREF_L30P_Y	B19[2]
1	IO_L31N_Y	C19
1	IO_L31P_Y	A18
1	IO_L32N_YY	D19
1	IO_VREF_L32P_YY	B18
1	IO_L33N_YY	C18
1	IO_L33P_YY	A17
1	IO_L34N_Y	D18
1	IO_L34P_Y	B17
1	IO_L35N_Y	E18
1	IO_L35P_Y	A16
1	IO_L36N_YY	C17
1	IO_VREF_L36P_YY	D17
1	IO_L37N_YY	B16
1	IO_L37P_YY	E17
1	IO_L38N_Y	A15
1	IO_L38P_Y	C16
1	IO_L39N_Y	B15
1	IO_L39P_Y	D16
1	IO_L40N_YY	A14
1	IO_VREF_L40P_YY	B14[1]
1	IO_L41N_YY	C15
1	IO_L41P_YY	A13
1	IO_L42N_Y	D15
1	IO_L42P_Y	B13
1	IO_L43N_Y	C14
1	IO_L43P_Y	A12
1	IO_L44N_YY	D14
1	IO_L44P_YY	C13
1	IO_L45N_YY	B12
1	IO_VREF_L45P_YY	D13
1	IO_L46N_Y	A11
1	IO_L46P_Y	C12

Table 22: **FG680 - XCV600E, XCV1000E, XCV1600E, XCV2000E**

Bank	Pin Description	Pin #
1	IO_L47N_Y	B11
1	IO_L47P_Y	C11
1	IO_L48N_YY	A10
1	IO_VREF_L48P_YY	D11
1	IO_L49N_YY	B10
1	IO_L49P_YY	C10
1	IO_L50N_Y	A9
1	IO_VREF_L50P_Y	D10[3]
1	IO_L51N_Y	B9
1	IO_L51P_Y	C9
1	IO_L52N_YY	A8
1	IO_VREF_L52P_YY	B8
1	IO_L53N_YY	D9
1	IO_L53P_YY	A7
1	IO_L54N_Y	C8
1	IO_L54P_Y	B7
1	IO_L55N_Y	D8
1	IO_L55P_Y	A6
1	IO_L56N_YY	C7
1	IO_VREF_L56P_YY	B6
1	IO_L57N_YY	D7
1	IO_L57P_YY	A5
1	IO_L58N_Y	C6
1	IO_VREF_L58P_Y	B5[1]
1	IO_L59N_Y	D6
1	IO_L59P_Y	A4
1	IO_WRITE_L60N_YY	B4
1	IO_CS_L60P_YY	D5
2	IO	D1
2	IO	F4
2	IO_DOUT_BUSY_L61P_YY	E3
2	IO_DIN_D0_L61N_YY	C2
2	IO_L62P_Y	D3
2	IO_L62N_Y	F3
2	IO_VREF_L63P	D2[1]

Table 24: **FG860 — XCV1000E, XCV1600E, XCV2000E**

Bank	Pin Description	Pin #
6	IO	AJ40
6	IO	AL41
6	IO	AN38
6	IO	AN42
6	IO	AP41
6	IO	AR39
6	IO_L211N_YY	AV41
6	IO_L211P_YY	AV42
6	IO_L212N_Y	AW40
6	IO_L212P_Y	AU41
6	IO_L213N_Y	AV39
6	IO_L213P_Y	AU42
6	IO_VREF_L214N_Y	AT41
6	IO_L214P_Y	AU38
6	IO_L215N	AT42
6	IO_L215P	AV40
6	IO_L216N_Y	AR41
6	IO_L216P_Y	AU39
6	IO_VREF_L217N_Y	AR42
6	IO_L217P_Y	AU40
6	IO_L218N_YY	AT38
6	IO_L218P_YY	AP42
6	IO_L219N_Y	AN41
6	IO_L219P_Y	AT39
6	IO_L220N_Y	AT40
6	IO_L220P_Y	AM40
6	IO_VREF_L221N_YY	AR38
6	IO_L221P_YY	AM41
6	IO_L222N_YY	AM42
6	IO_L222P_YY	AR40
6	IO_VREF_L223N_Y	AL40[2]
6	IO_L223P_Y	AP38
6	IO_L224N_Y	AP39
6	IO_L224P_Y	AL42
6	IO_VREF_L225N_YY	AP40
6	IO_L225P_YY	AK40
6	IO_L226N_YY	AK41
6	IO_L226P_YY	AN39
6	IO_L227N_Y	AK42
6	IO_L227P_Y	AN40
6	IO_VREF_L228N_YY	AM38
6	IO_L228P_YY	AJ41
6	IO_L229N_YY	AJ42
6	IO_L229P_YY	AM39
6	IO_L230N_Y	AH40
6	IO_L230P_Y	AH41
6	IO_L231N_Y	AL38
6	IO_L231P_Y	AH42
6	IO_L232N_Y	AL39
6	IO_L232P_Y	AG41
6	IO_L233N	AK39
6	IO_L233P	AG40
6	IO_L234N_Y	AJ38
6	IO_L234P_Y	AG42
6	IO_VREF_L235N_Y	AF42
6	IO_L235P_Y	AJ39
6	IO_L236N_YY	AF41
6	IO_L236P_YY	AH38
6	IO_L237N_Y	AE42
6	IO_L237P_Y	AH39
6	IO_L238N_Y	AG38
6	IO_L238P_Y	AE41
6	IO_VREF_L239N_YY	AG39
6	IO_L239P_YY	AD42
6	IO_L240N_YY	AD40
6	IO_L240P_YY	AF39
6	IO_L241N_Y	AD41
6	IO_L241P_Y	AE38
6	IO_L242N_Y	AE39
6	IO_L242P_Y	AC40
6	IO_VREF_L243N_YY	AD38
6	IO_L243P_YY	AC41
6	IO_L244N_YY	AB42
6	IO_L244P_YY	AC38

Table 25: **FG860 Differential Pin Pair Summary XCV1000E, XCV1600E, XCV2000E**

Pair	Bank	P Pin	N Pin	AO	Other Functions
120	3	AH1	AL5	1	-
121	3	AH2	AM4	3	-
122	3	AH3	AM5	√	D5
123	3	AJ1	AN3	√	VREF
124	3	AN4	AJ3	2	-
125	3	AN5	AK1	√	-
126	3	AK2	AP4	√	VREF
127	3	AK3	AP5	2	-
128	3	AR3	AL2	5	VREF
129	3	AR4	AL3	√	-
130	3	AM1	AT3	√	VREF
131	3	AM2	AT4	1	-
132	3	AT5	AN1	2	-
133	3	AU3	AN2	√	-
134	3	AP1	AP2	1	VREF
135	3	AR1	AV3	2	-
136	3	AR2	AT1	4	-
137	3	AV4	AT2	2	VREF
138	3	AU1	AU5	1	-
139	3	AU2	AW3	3	-
140	3	AV1	AW5	√	INIT
141	4	AV6	BA4	√	-
142	4	AY4	BA5	2	-
143	4	AW6	BB5	1	-
144	4	BA6	AY5	1	VREF
145	4	BB6	AY6	5	-
146	4	BA7	AV7	√	-
147	4	BB7	AW7	√	VREF
148	4	AY7	BB8	5	-
149	4	BA9	AV8	5	-
150	4	AW8	BA10	√	-
151	4	BB10	AY8	√	VREF
152	4	AV9	BA11	1	-
153	4	BB11	AW9	1	VREF

Table 25: **FG860 Differential Pin Pair Summary XCV1000E, XCV1600E, XCV2000E**

Pair	Bank	P Pin	N Pin	AO	Other Functions
154	4	AY9	BA12	√	-
155	4	BB12	AV10	√	VREF
156	4	BA13	AW10	2	-
157	4	BB13	AY10	2	-
158	4	AV11	BA14	√	VREF
159	4	AW11	BB14	√	-
160	4	AV12	BA15	2	-
161	4	AW12	AY15	1	-
162	4	AW13	BB15	1	-
163	4	AV14	BA16	5	-
164	4	AW14	AY16	√	-
165	4	BB16	AV15	√	VREF
166	4	AY17	AW15	5	-
167	4	BB17	AU16	5	-
168	4	AV16	AY18	√	-
169	4	AW16	BA18	√	VREF
170	4	BB19	AW17	1	-
171	4	AY19	AV18	1	-
172	4	AW18	BB20	√	-
173	4	AY20	AV19	√	VREF
174	4	BB21	AW19	2	-
175	4	AY21	AV20	2	VREF
176	5	AW20	AW21	NA	IO_LVDS_DLL
177	5	BB22	AW22	2	VREF
178	5	BB23	AW23	2	-
179	5	AV23	BA23	√	VREF
180	5	AW24	BB24	√	-
181	5	AY24	AW25	1	-
182	5	BA24	AV25	1	-
183	5	AW26	AY25	√	VREF
184	5	AV26	BA25	√	-
185	5	BB26	AV27	5	-
186	5	AY26	AU27	5	-
187	5	AW28	BB27	√	VREF

Table 27: **FG900 Differential Pin Pair Summary XCV600E, XCV1000E, XCV1600E**

Pair	Bank	P Pin	N Pin	AO	Other Functions
120	3	AA30	W24	4	-
121	3	AA29	V20	1	-
122	3	Y27	W23	NA	-
123	3	Y26	AB30	√	D5
124	3	V21	AA28	√	VREF
125	3	Y25	AA27	4	-
126	3	W22	Y23	4	-
127	3	Y24	AB28	4	VREF
128	3	AC30	AA25	√	-
129	3	W21	AA24	2	-
130	3	AB26	AD30	√	-
131	3	Y22	AC27	√	VREF
132	3	AD28	AB25	2	-
133	3	AC26	AE30	4	-
134	3	AD27	AF30	√	-
135	3	AF29	AB24	1	VREF
136	3	AB23	AE28	4	-
137	3	AG30	AC25	3	-
138	3	AE26	AG29	4	VREF
139	3	AH30	AC24	1	-
140	3	AF28	AD25	NA	-
141	3	AH29	AA22	√	INIT
142	4	AF27	AK28	√	-
143	4	AG26	AH27	4	-
144	4	AD23	AJ27	2	-
145	4	AB21	AF25	2	VREF
146	4	AC22	AH26	2	-
147	4	AA21	AG25	√	-
148	4	AJ26	AD22	√	VREF
149	4	AA20	AH25	1	-
150	4	AC21	AF24	1	-
151	4	AG24	AK26	√	-
152	4	AJ24	AF23	√	VREF
153	4	AE23	AB20	2	-

Table 27: **FG900 Differential Pin Pair Summary XCV600E, XCV1000E, XCV1600E**

Pair	Bank	P Pin	N Pin	AO	Other Functions
154	4	AC20	AG23	2	-
155	4	AF22	AE22	√	-
156	4	AJ22	AG22	√	VREF
157	4	AK24	AD20	NA	-
158	4	AA19	AF21	4	-
159	4	AH22	AA18	NA	VREF
160	4	AG21	AK23	NA	-
161	4	AH21	AD19	4	-
162	4	AE20	AJ21	2	-
163	4	AG20	AF20	2	-
164	4	AC18	AF19	2	-
165	4	AJ20	AE19	√	-
166	4	AK22	AH20	√	VREF
167	4	AG19	AB17	1	-
168	4	AJ19	AD17	1	-
169	4	AA16	AA17	√	-
170	4	AK21	AB16	√	VREF
171	4	AG18	AK20	2	-
172	4	AK19	AD16	2	-
173	4	AE16	AE17	√	-
174	4	AG17	AJ17	√	VREF
175	4	AD15	AH17	NA	-
176	4	AG16	AK17	4	VREF
177	5	AF16	AH16	NA	IO_ LVDS_DLL
178	5	AC15	AG15	4	VREF
179	5	AB15	AF15	√	-
180	5	AA15	AF14	√	VREF
181	5	AH15	AK15	√	-
182	5	AB14	AF13	2	-
183	5	AH14	AJ14	2	-
184	5	AE14	AG13	√	VREF
185	5	AK13	AD13	√	-
186	5	AE13	AF12	1	-
187	5	AC13	AA13	1	-

Table 28: **FG1156 — XCV1000E, XCV1600E, XCV2000E, XCV2600E, XCV3200E**

Bank	Pin Description	Pin #
1	IO_L66P_Y	E24
1	IO_L67N_YY	A26
1	IO_VREF_L67P_YY	C25
1	IO_L68N_YY	F24
1	IO_L68P_YY	B26
1	IO_L69N	K23[5]
1	IO_L69P	F25[4]
1	IO_L70N_Y	C26
1	IO_VREF_L70P_Y	H24[2]
1	IO_L71N_Y	G24
1	IO_L71P_Y	A27
1	IO_L72N	B27[5]
1	IO_L72P	G25[4]
1	IO_L73N_YY	E26
1	IO_VREF_L73P_YY	C27
1	IO_L74N_YY	J24
1	IO_L74P_YY	B28
1	IO_L75N	K24[5]
1	IO_L75P	H25[4]
1	IO_L76N_Y	D27
1	IO_L76P_Y	F26
1	IO_L77N_Y	G26
1	IO_L77P_Y	C28
1	IO_L78N_YY	E27[5]
1	IO_L78P_YY	J25[4]
1	IO_L79N_YY	A30
1	IO_VREF_L79P_YY	H26
1	IO_L80N_YY	G27
1	IO_L80P_YY	B29
1	IO_L81N_Y	F27
1	IO_L81P_Y	C29
1	IO_L82N_Y	E28
1	IO_VREF_L82P_Y	F28
1	IO_L83N_Y	L25

Table 28: **FG1156 — XCV1000E, XCV1600E, XCV2000E, XCV2600E, XCV3200E**

Bank	Pin Description	Pin #
1	IO_L83P_Y	B30
1	IO_L84N	B31
1	IO_L84P	E29
1	IO_WRITE_L85N_YY	A31
1	IO_CS_L85P_YY	D30
2	IO	F31[3]
2	IO	J32
2	IO	K27[3]
2	IO	K31[3]
2	IO	L28[3]
2	IO	L30[3]
2	IO	M32[3]
2	IO	N26
2	IO	N28[3]
2	IO	P25[3]
2	IO	U26[3]
2	IO	U30
2	IO	U32[3]
2	IO	U34
2	IO_D2	M30
2	IO_DOUT_BUSY_L86P_YY	D32
2	IO_DIN_D0_L86N_YY	J27
2	IO_L87P_Y	E31
2	IO_L87N_Y	F30
2	IO_L88P_Y	G29
2	IO_L88N_Y	F32
2	IO_VREF_L89P_Y	E32
2	IO_L89N_Y	G30
2	IO_L90P	M25
2	IO_L90N	G31
2	IO_L91P_Y	L26
2	IO_L91N_Y	D33
2	IO_VREF_L92P_Y	D34